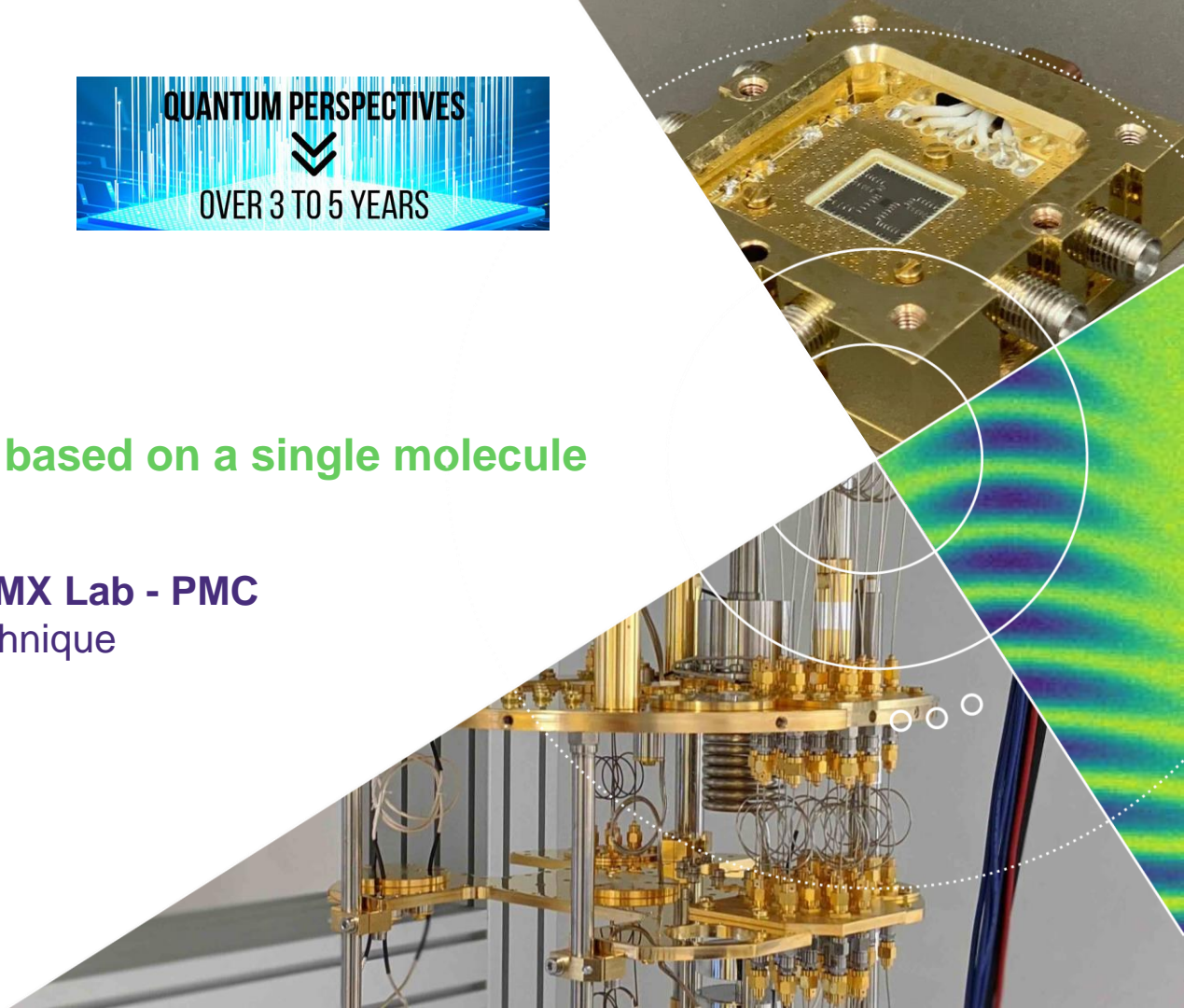


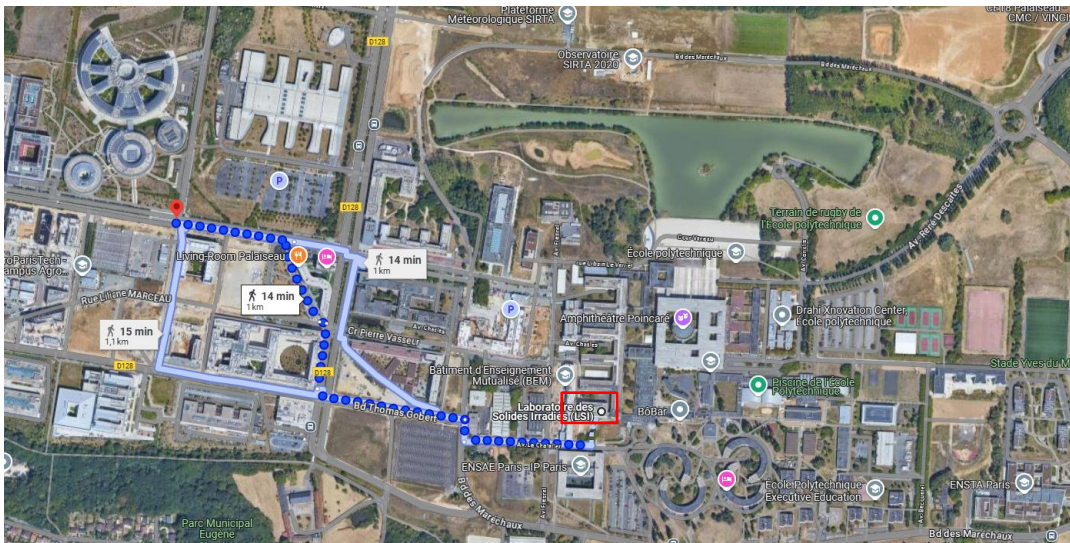


Superconducting qubit based on a single molecule The nanotube gatemon

Jean-Damien PILLET - QCMX Lab - PMC
Professeur à l'Ecole Polytechnique



Where we are



QCMX Lab PMC, X

Bâtiment 83
1^{er} étage
83-20-20



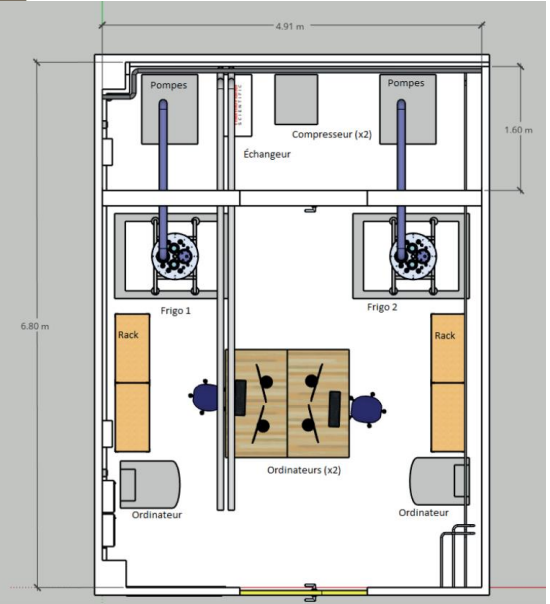
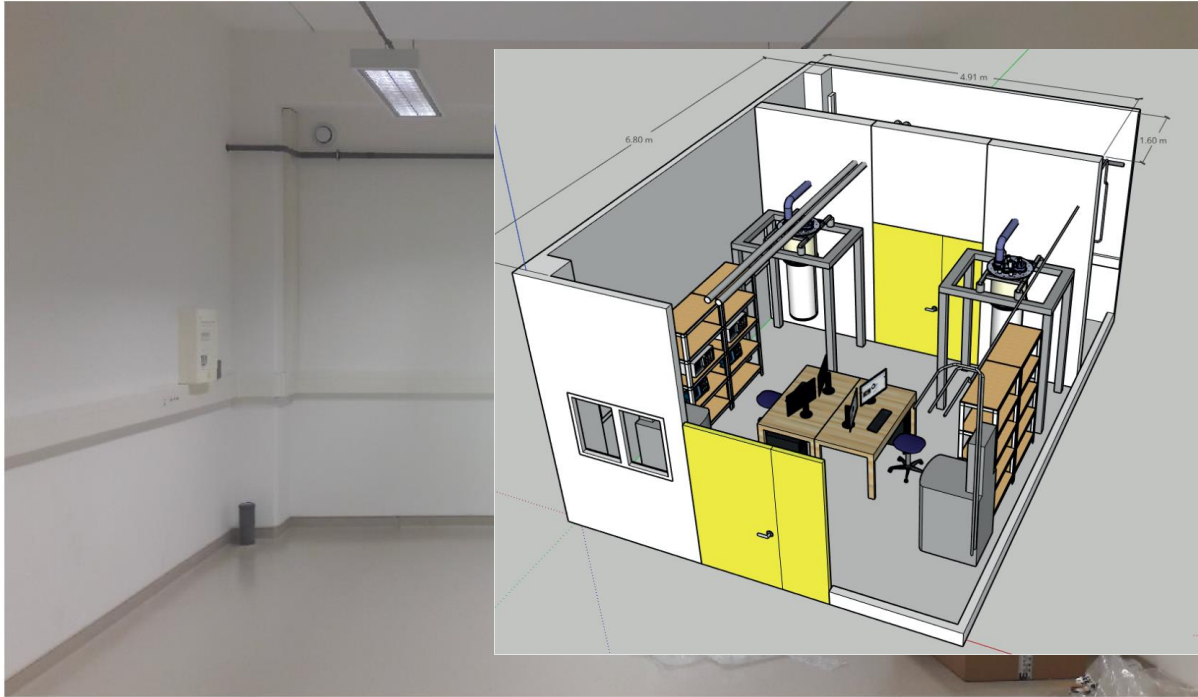


J.-D. Pillet



L. Bretheau

At the beginning,
there was... two
empty rooms and
two physicists.



Construction work (masonry, plumbing, electricity)

*Help of P.-E. Coulon ,
B. Konate & DPI*

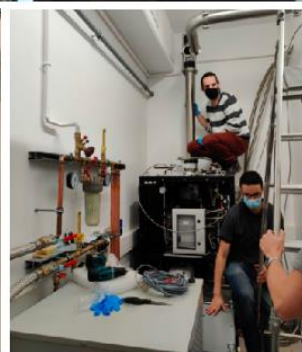
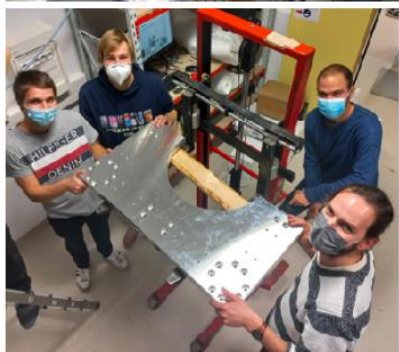


Cryogen-free dilution refrigerator (7 mK)

+ Electronics instruments



2nd Cryostat (10 mK, 1T / 1T / 3T, bottom loader)



Preparation room

Wirebonding machine
+ fume hood



Microscope +
workshop + soldering

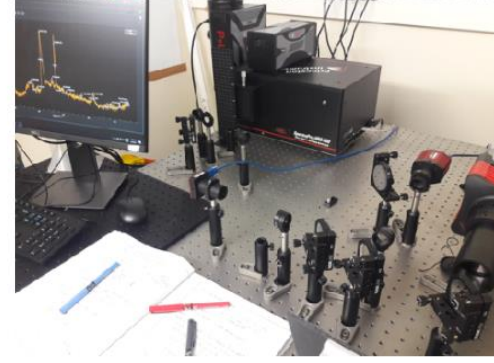
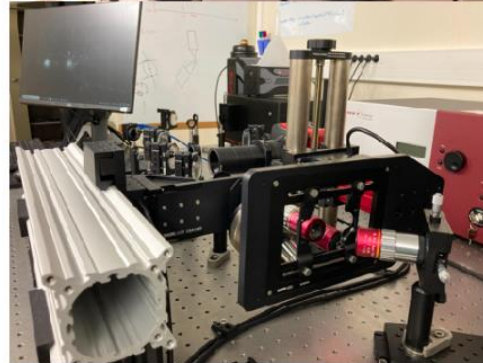
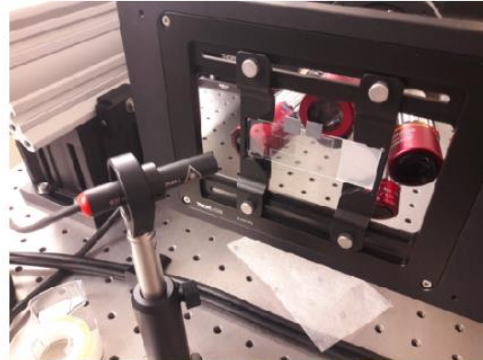


Furnace & gaz
handling system



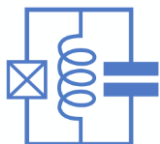
Carbon Nanotube Platform: Optical Characterization + Transfer

Supercontinuum laser, spectrometer, transfer station

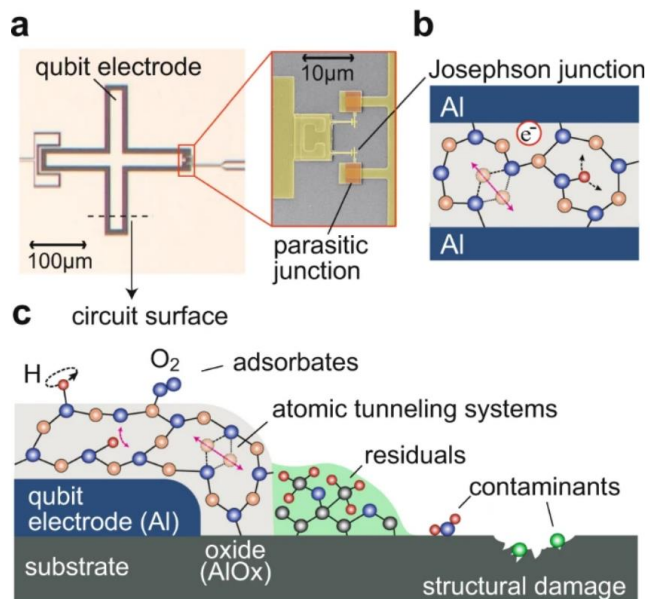


Everton Arrighi
Maxime Hantute
Landry Bretheau
Hannes Riechert
Joël Griesmar
Samy Annabi
Jean-Damien Pillet
Hadrien Duprez

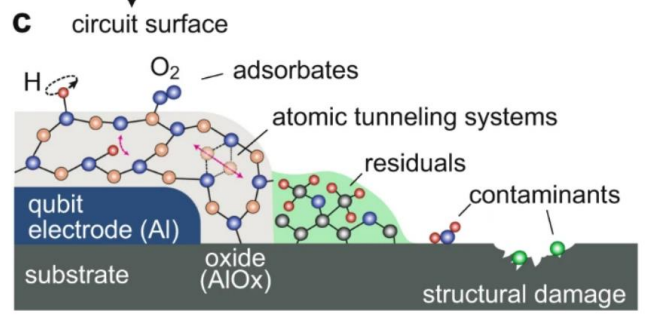
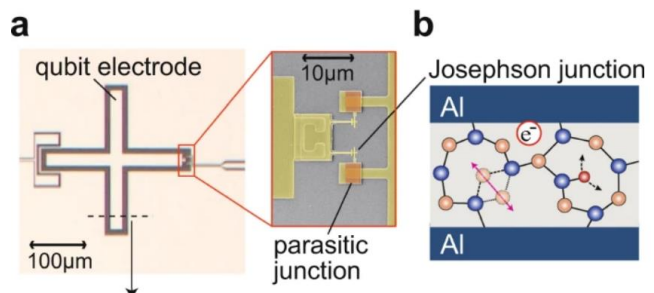




Superconducting qubits Benjamin Huard's talk

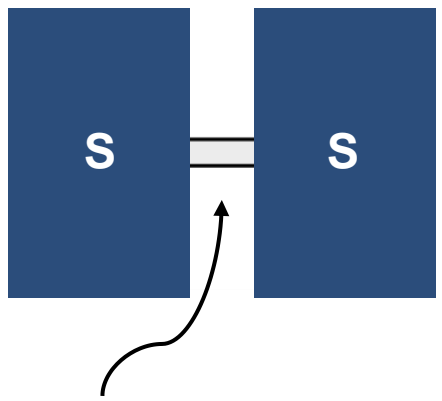


[Lisenfeld et al. (KIT), npj QI 2019]

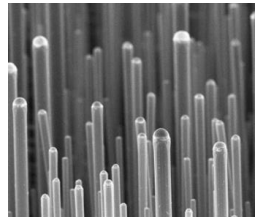
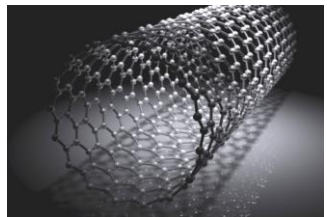
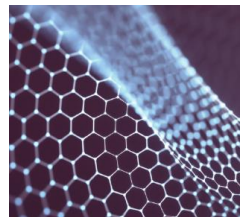


[Lisenfeld et al. (KIT), npj QI 2019]

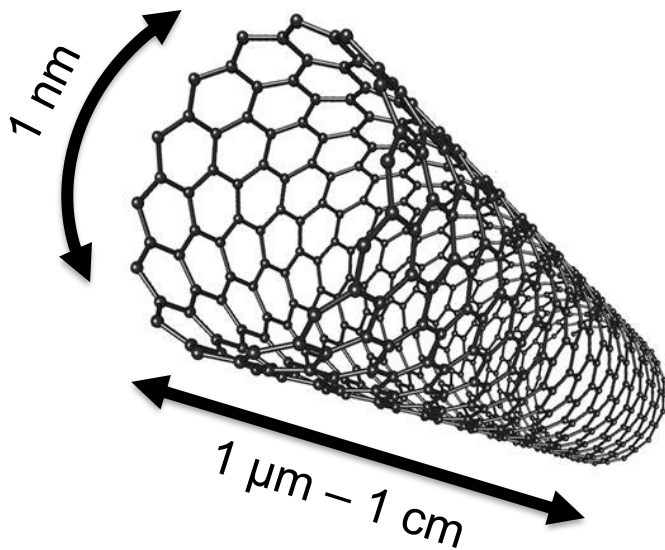
Hybrid Josephson junctions



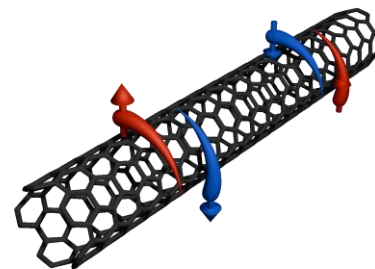
Perfectly crystalline quantum conductor
 (graphene, carbon nanotube, nanowires...)

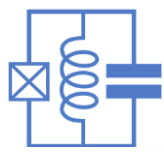
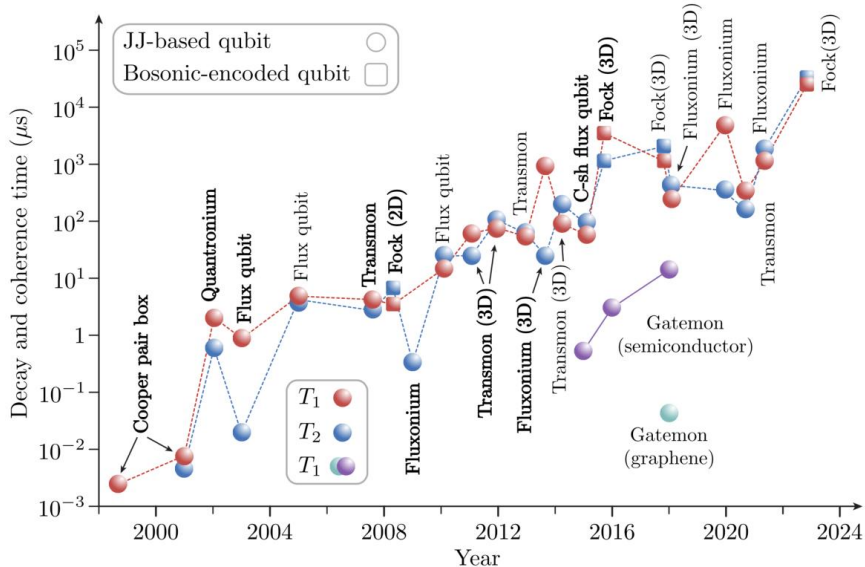


Hexagonal lattice of carbon atoms

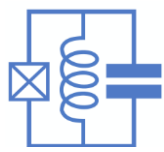
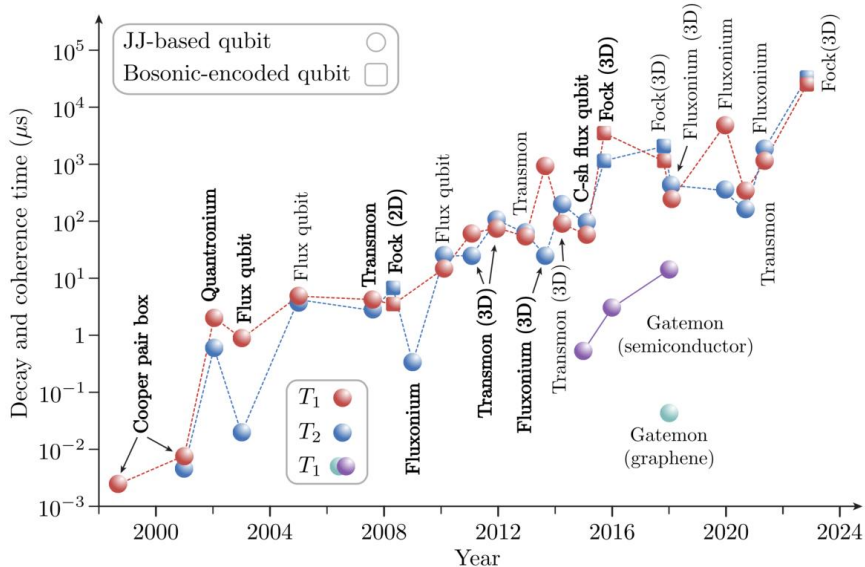


- Perfect crystalline compound
- Very few degrees of freedom
- Good electrical conductor
- Fundamentally interesting



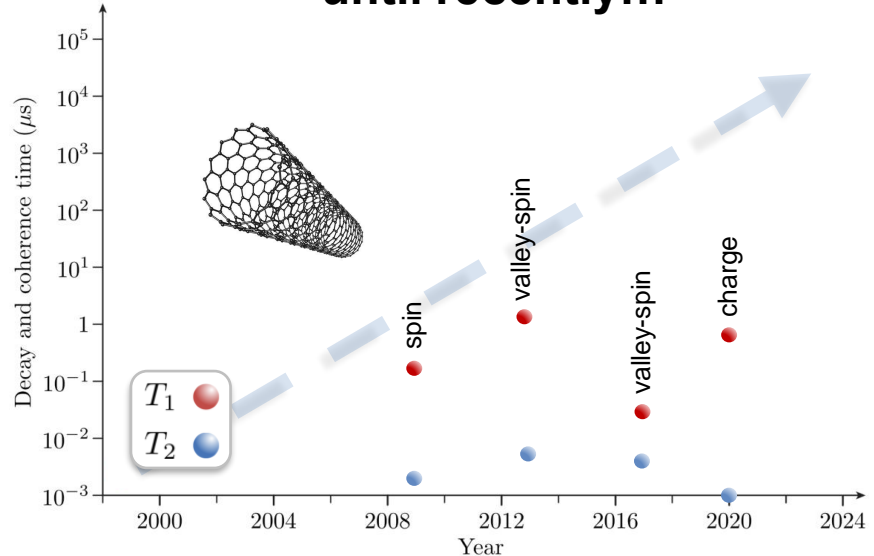


Superconducting qubits
Benjamin Huard's talk



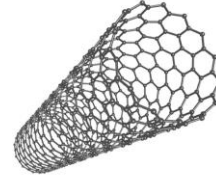
Superconducting qubits
Benjamin Huard's talk

Quantum control of nanotube qubit until recently...



Very low coherence time...
 Limited by charge noise
 ⇒ Sample quality is too low

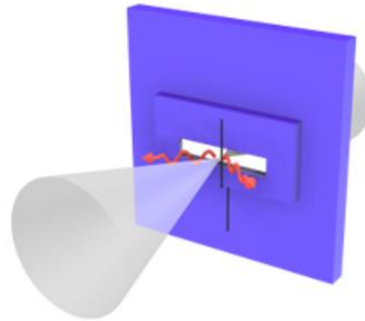
QCMX CNT-platform



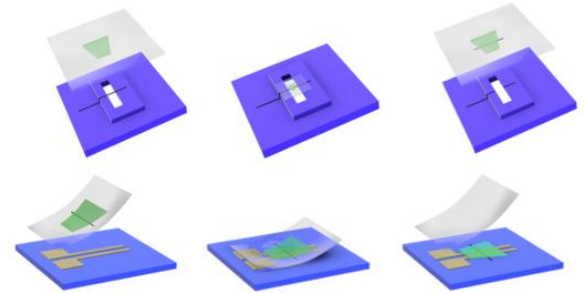
Growth



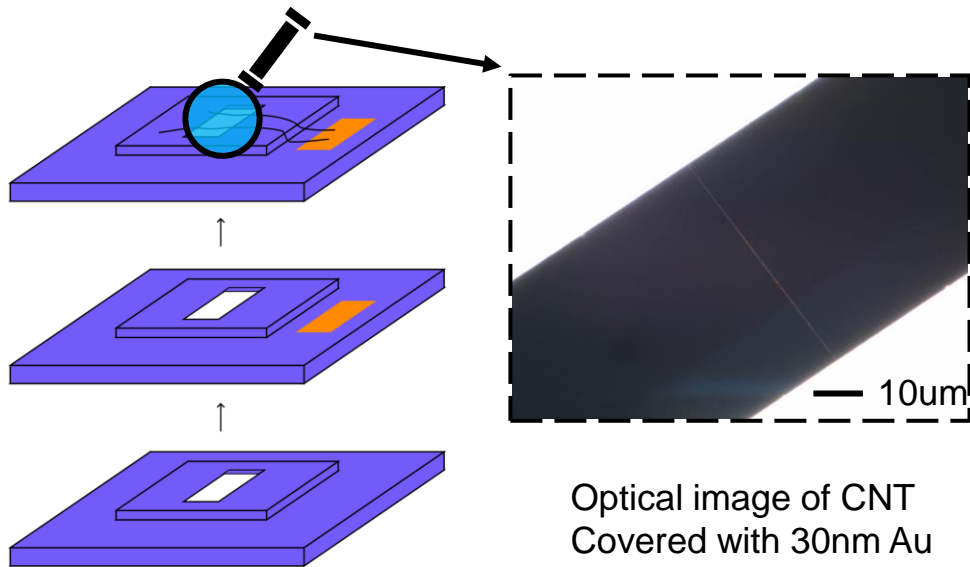
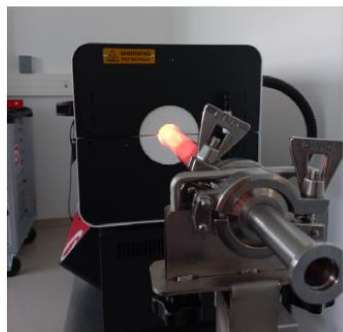
Characterization



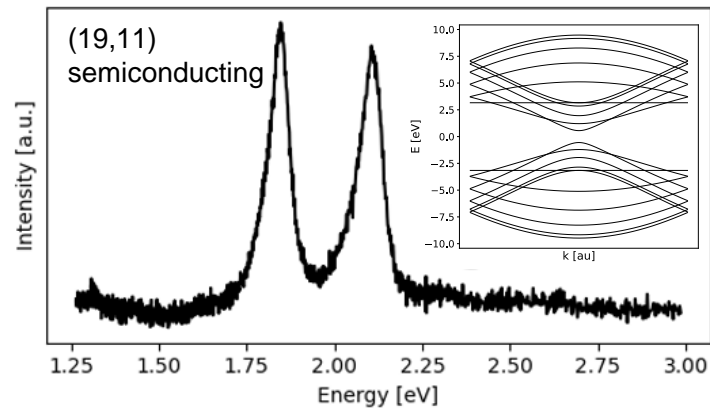
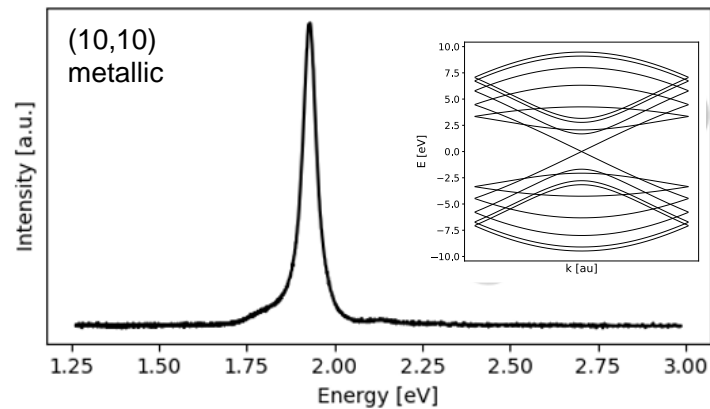
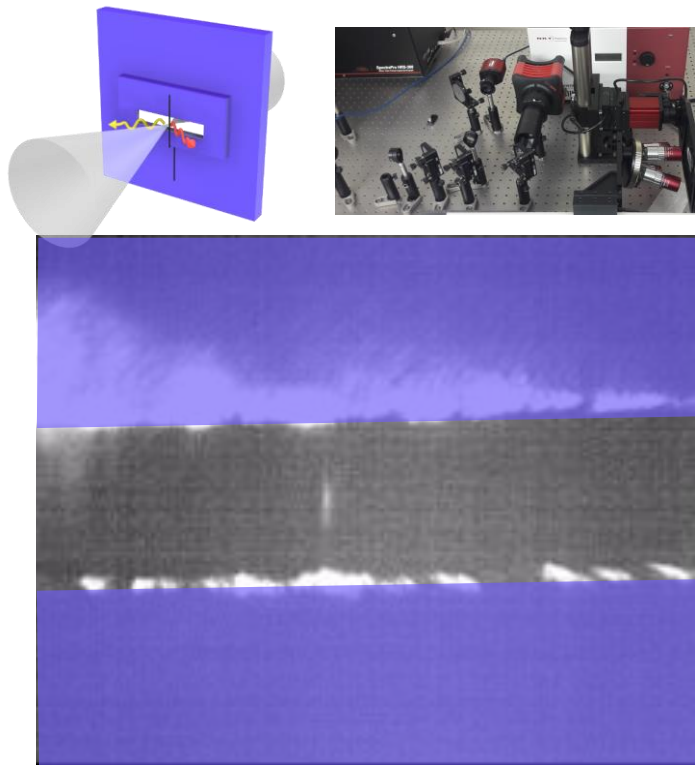
Integration by transfer



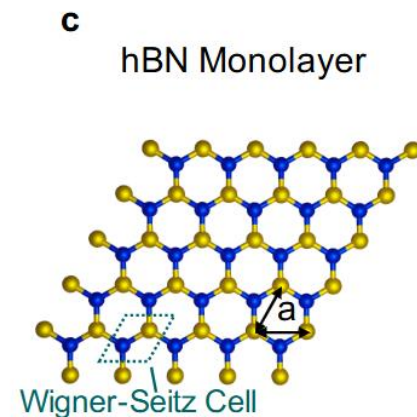
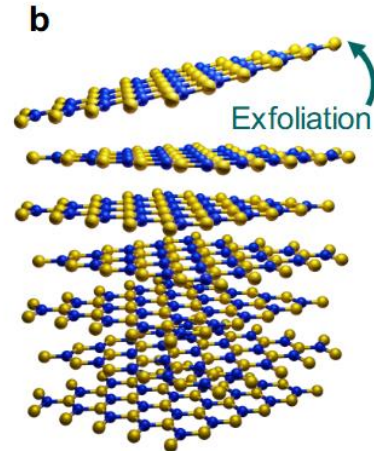
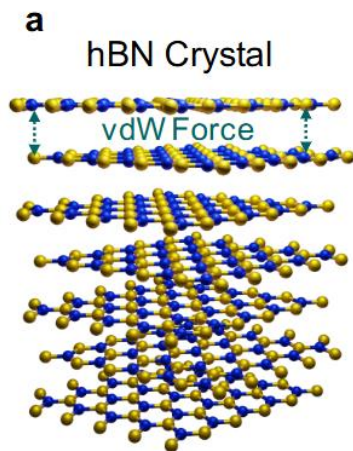
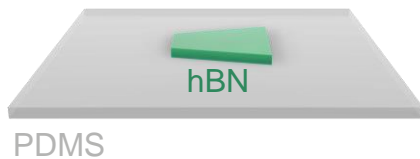
Furnace (~1000 °C) + Ar / H₂ / CH₄ flow



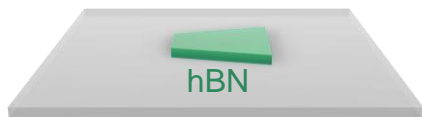
Real time and real space imaging



Using hexagonal Boron Nitride (hBN) as a perfectly crystalline substrate

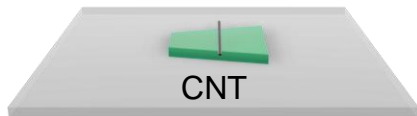


From Andreas Paul Gottscholl PhD thesis

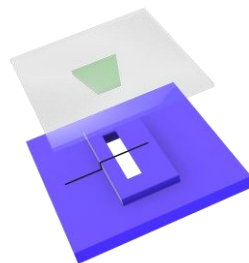


hBN

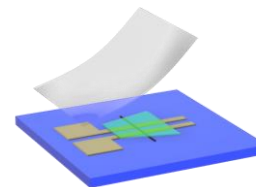
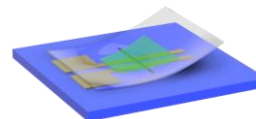
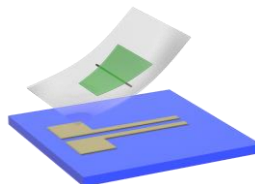
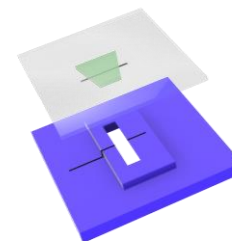
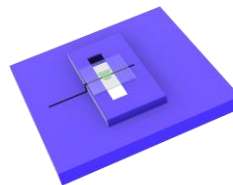
PDMS



CNT

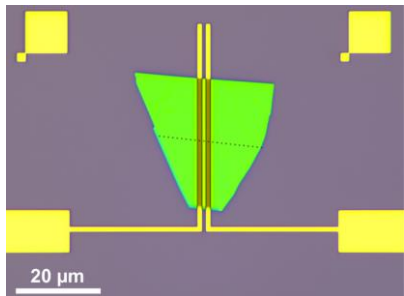


Pickup



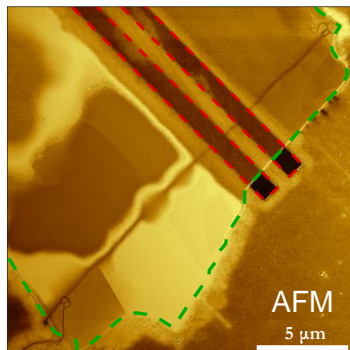
Transfer

Help from: F. Cadiz, S. Park (LPMC), R. Ribeiro (C2N), A. Vecchiola (CNRS-THALES), AdN SPEC (CEA Saclay), Watanabe & Taniguchi



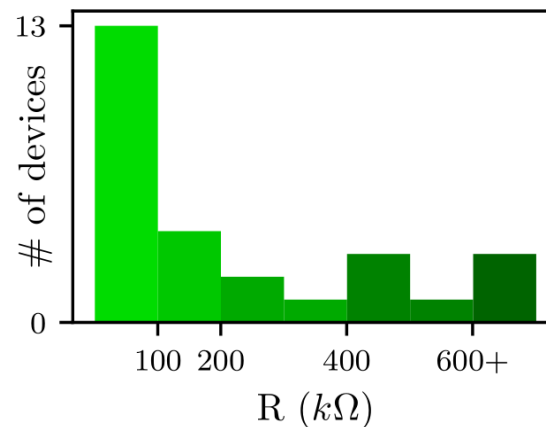
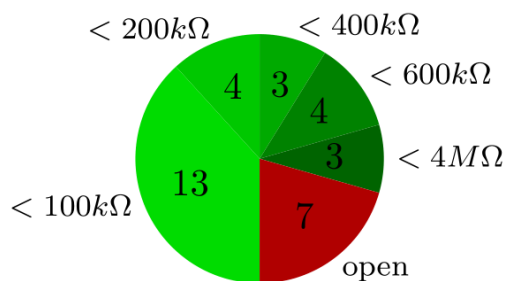
- Substrate
- hBN
- Electrodes
- CNT

Superconducting (Nb)

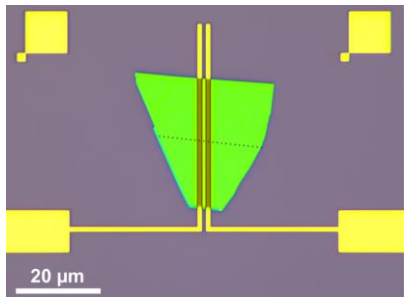


- Electrodes
- hBN

Successful devices (40%)

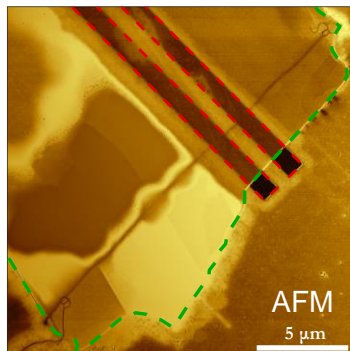


(pessimistic estimation)

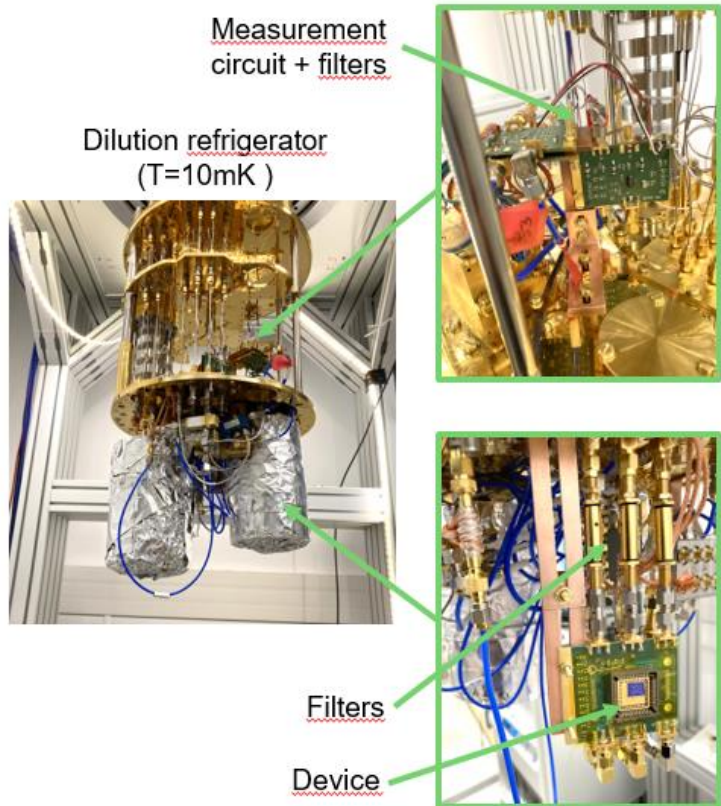


- Substrate
- hBN
- Electrodes
- CNT

Superconducting (Nb)



- Electrodes
- hBN



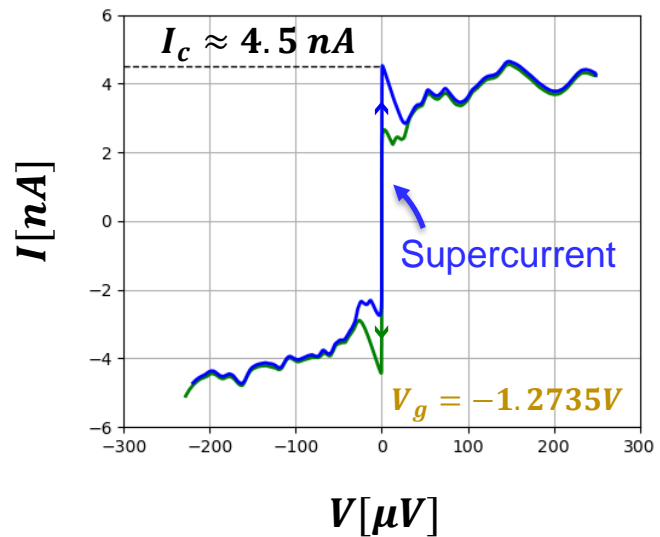
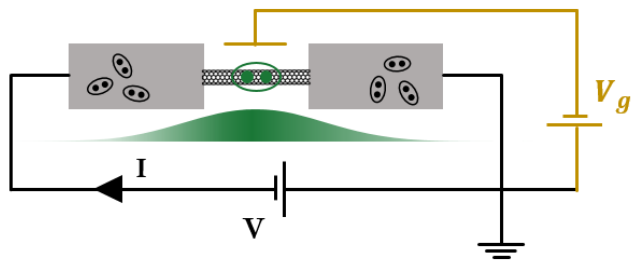
Measurement circuit + filters

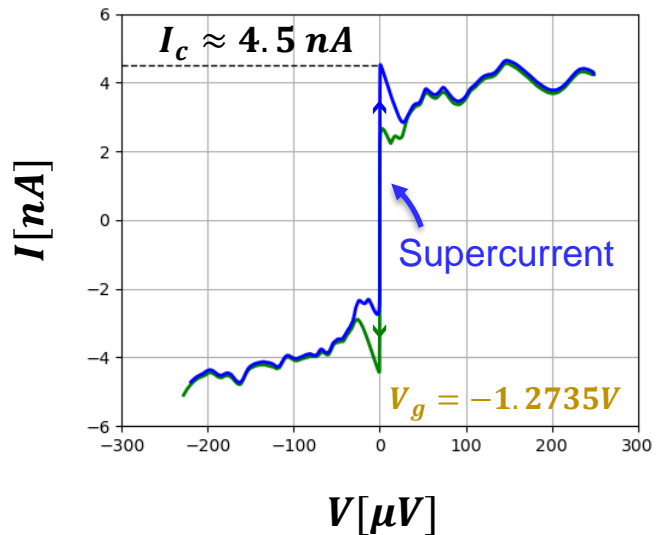
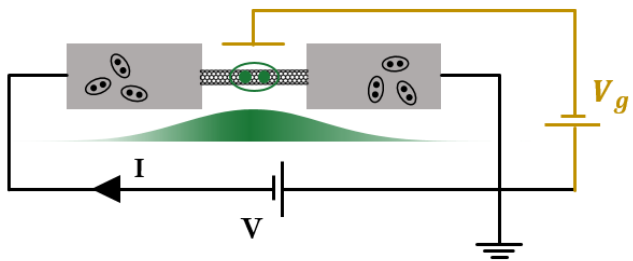
Dilution refrigerator (T=10mK)

Filters

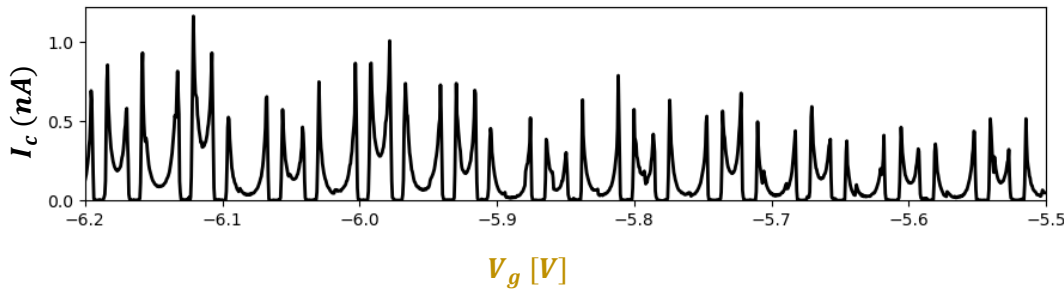
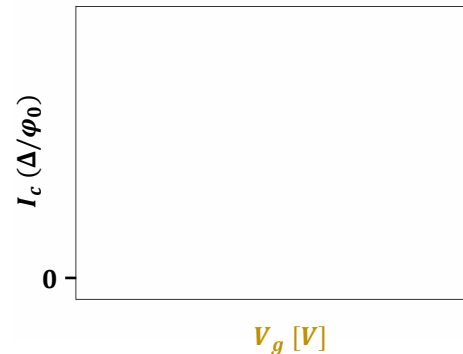
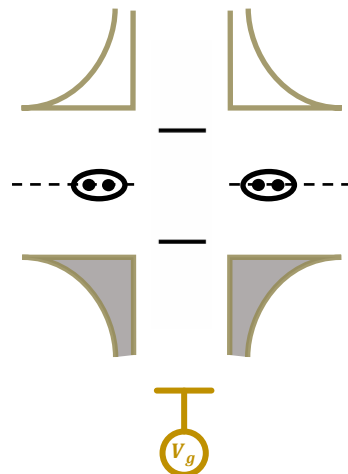
Device



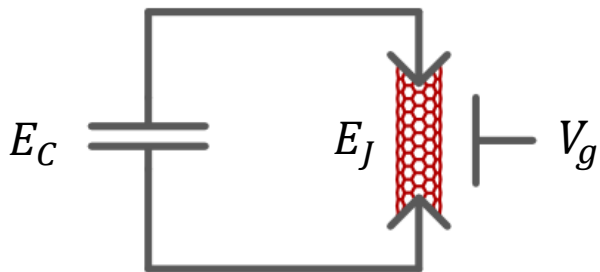




Gate tunable supercurrent

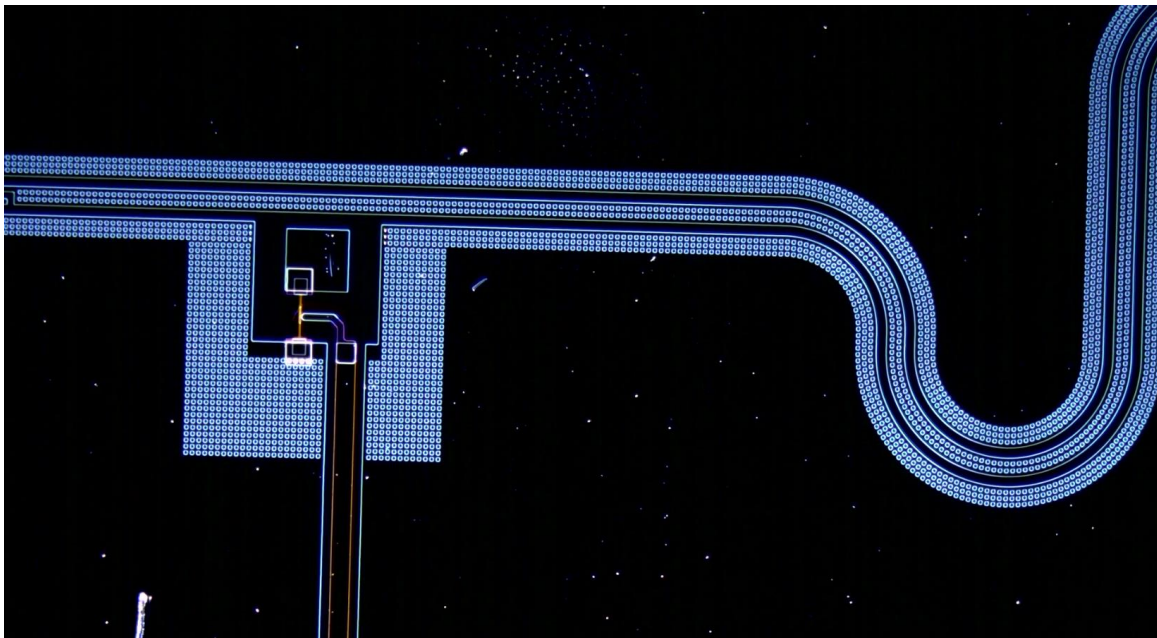


Nanotube gatemon Gate tunable qubit

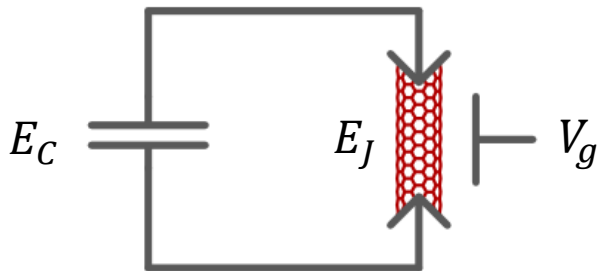


$$E_J \sim \varphi_0 I_c$$

$$\omega_q \approx \sqrt{8E_C E_J}$$



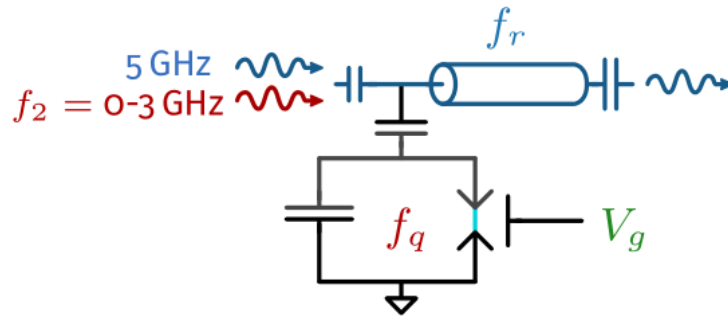
Nanotube gatemon Gate tunable qubit



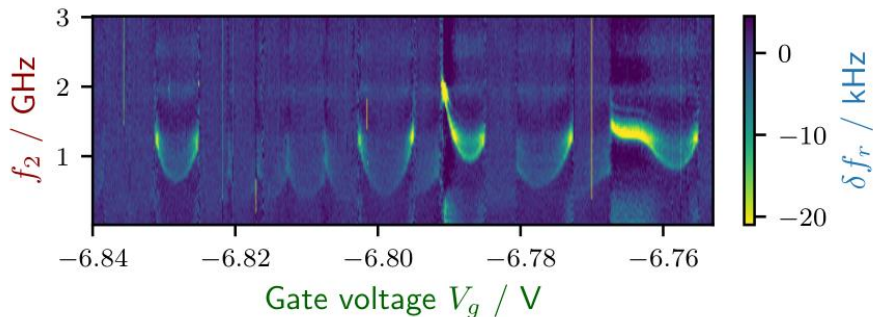
$$E_J \sim \varphi_0 I_c$$

$$\omega_q \approx \sqrt{8E_C E_J}$$

cQED architecture

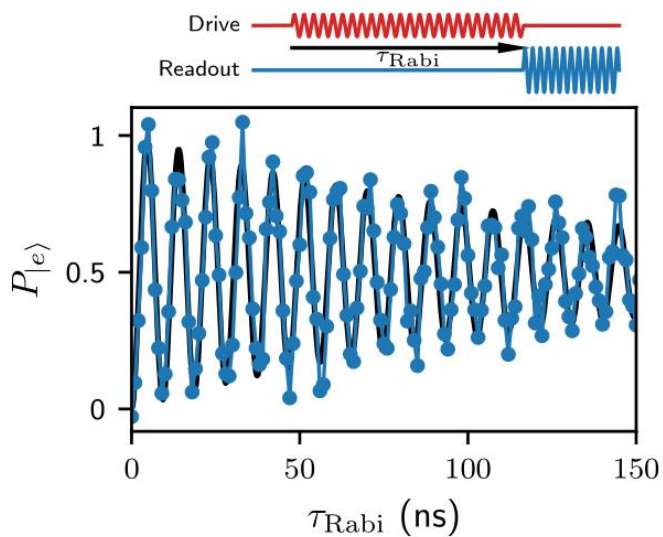
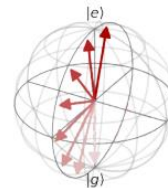
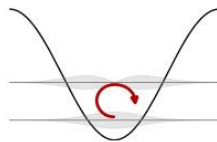


Qubit frequency



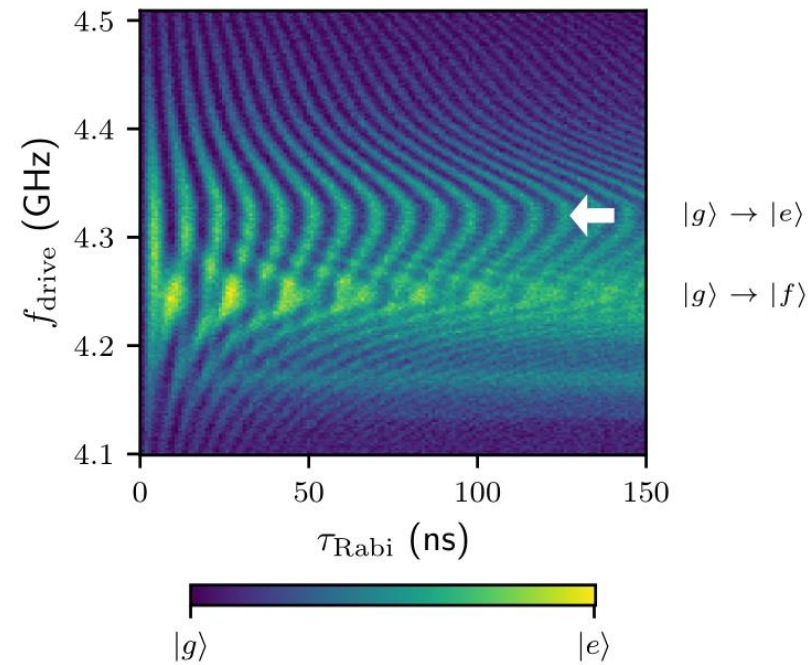
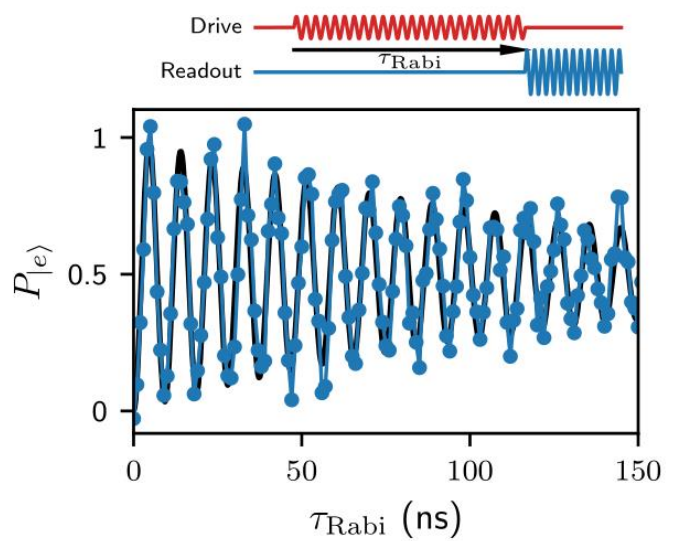
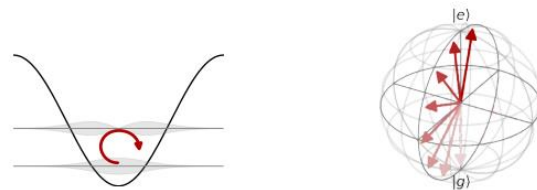
Rabi oscillations

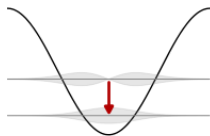
Coherent oscillations between ground and excited state



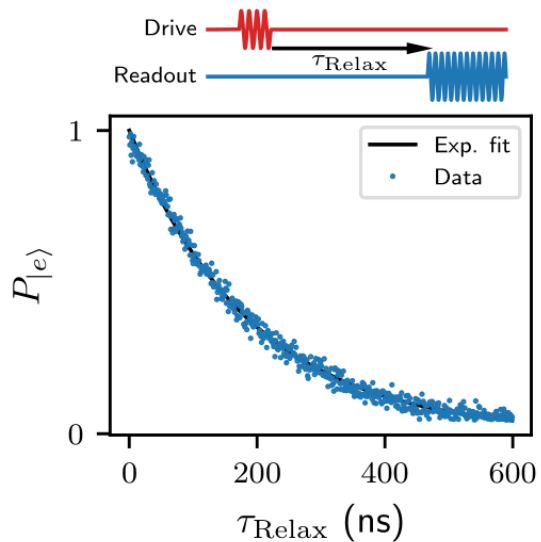
Rabi oscillations

Coherent oscillations between ground and excited state

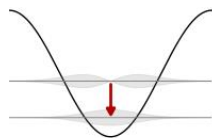




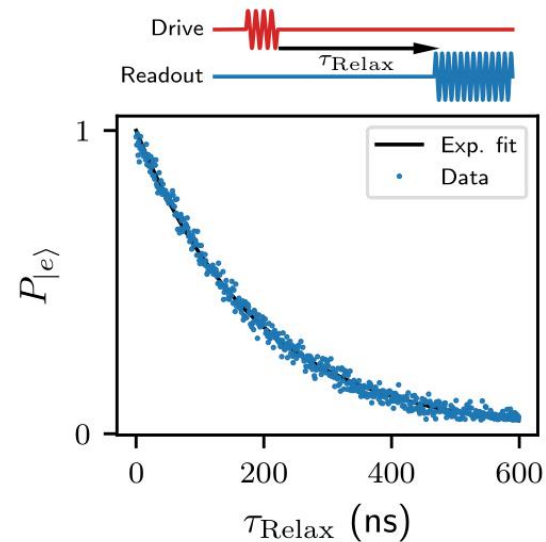
Relaxation
photon loss



$$T_1 = (191 \pm 2) \text{ ns}$$

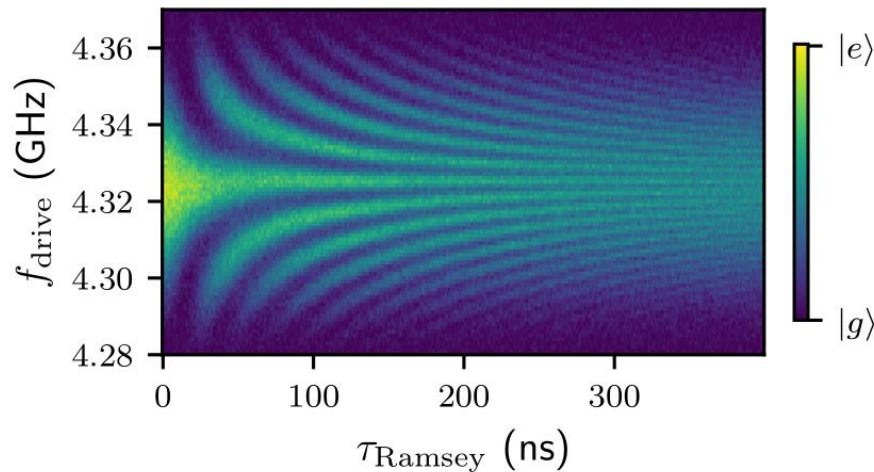
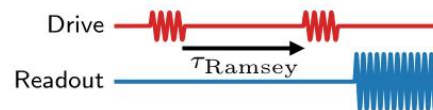
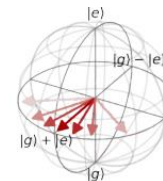


Relaxation
photon loss



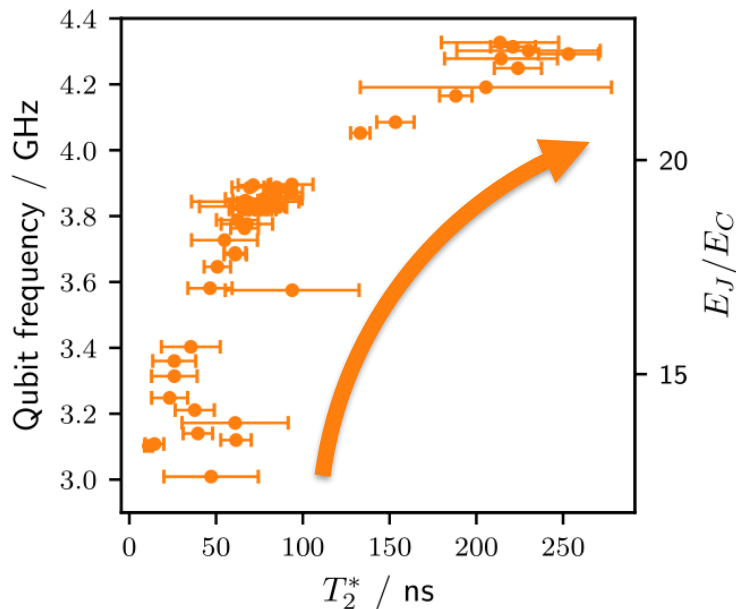
$$T_1 = (191 \pm 2) \text{ ns}$$

Coherence time
 f_q fluctuations

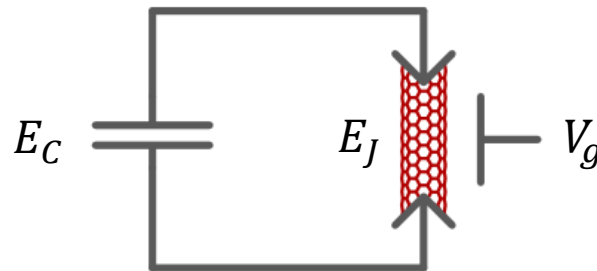


$$T_2^* = (200 \pm 13) \text{ ns}$$

Increasing E_J/E_C
decreases charge sensitivity



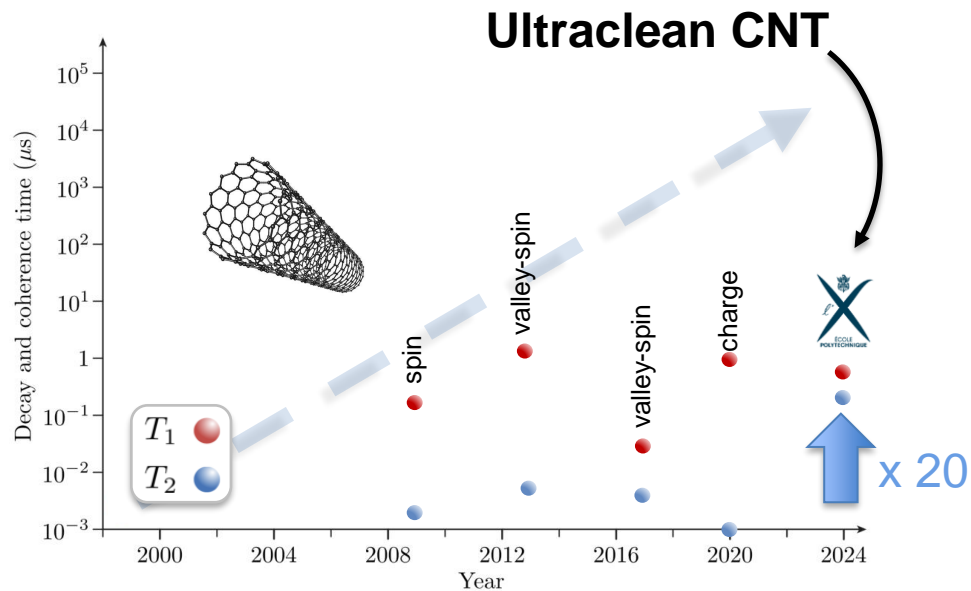
(charge insensitivity)



$$E_J \sim \varphi_0 I_c$$

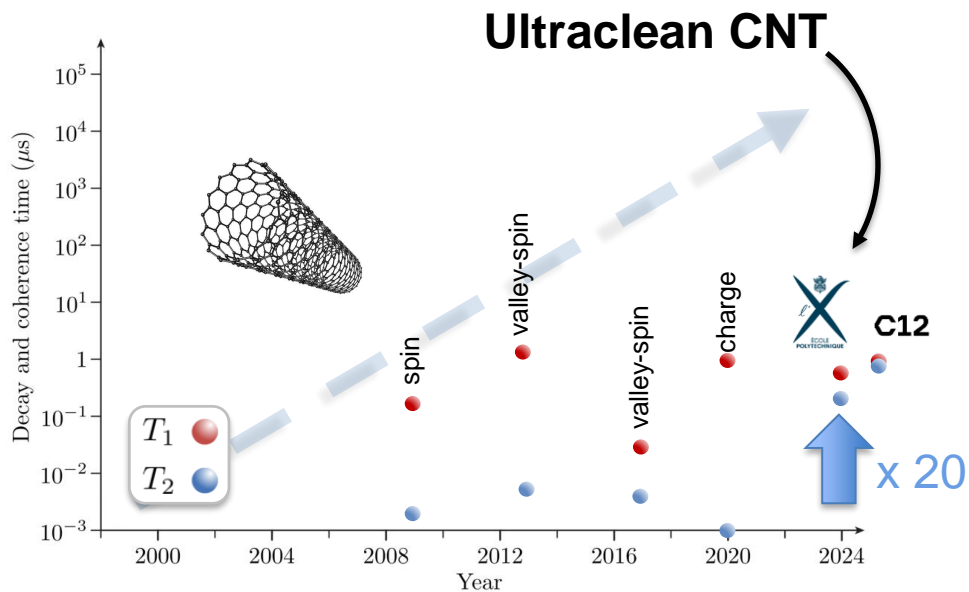
$$\omega_q \approx \sqrt{8E_C E_J}$$

There is no hard limit on E_J/E_C
 \Rightarrow We can increase T_2^* further !



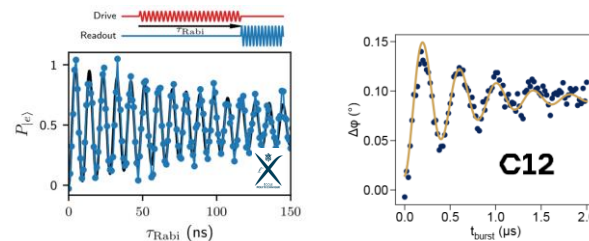
We gain **one order of magnitude on T_2^***
on the first attempt

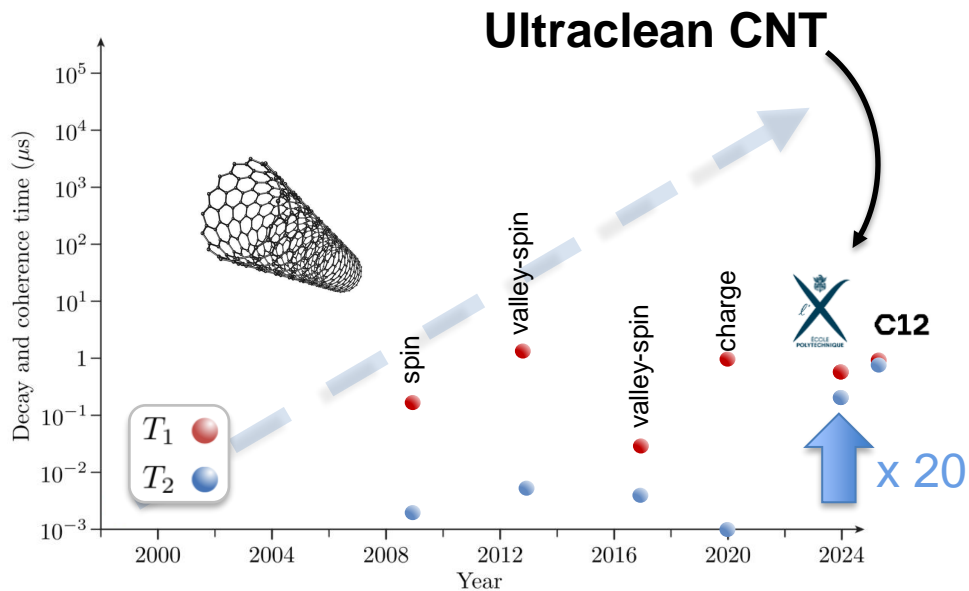
Still limited by charge noise...



We gain **one order of magnitude on T_2^***
on the first attempt

Still limited by charge noise...





We gain **one order of magnitude on T_2^***
on the first attempt

Still limited by charge noise...

A lot of room for improvement

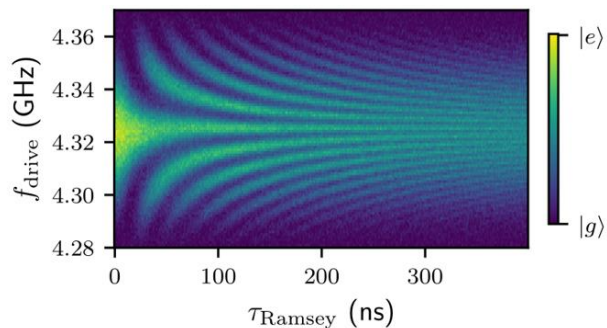
- Increase E_J/E_C
- Full hBN encapsulation
- Screen Si substrate with a bottom gate



Dall-e's artist view of the CNT gatemon

⇒ **Adjust design and nanofab**

Nanotube qubits with ultraclean nanotube



Cat qubits
(Alice and Bob)

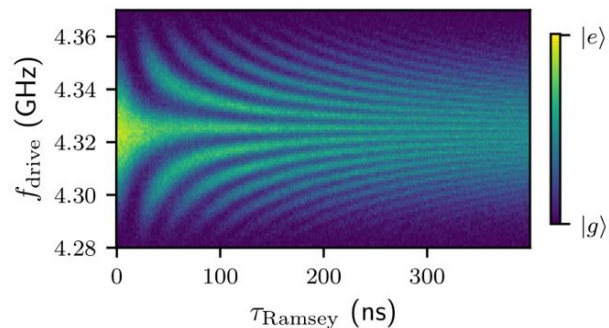
Spin qubits in silicon
(TU Delft)

Rydberg atoms
(Harvard, Pasqal)

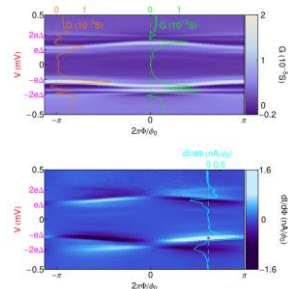
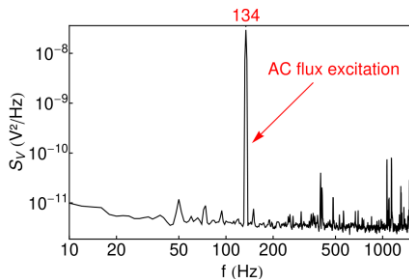
Superconducting qubits
(IBM, Google)



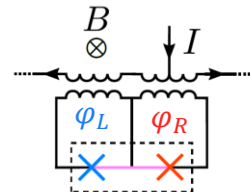
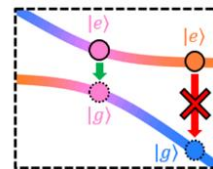
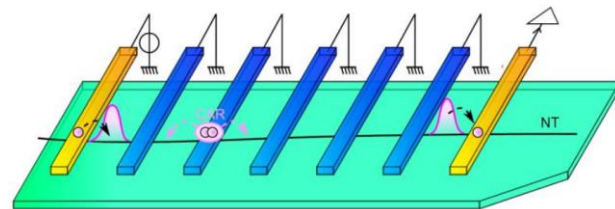
Nanotube qubits with ultraclean nanotube



Quantum sensors



Quantum simulators and protected fermionic qubit



Qubit

Quantum control

2-qubits gate

Scaling up

Error Correction

Quantum processor